

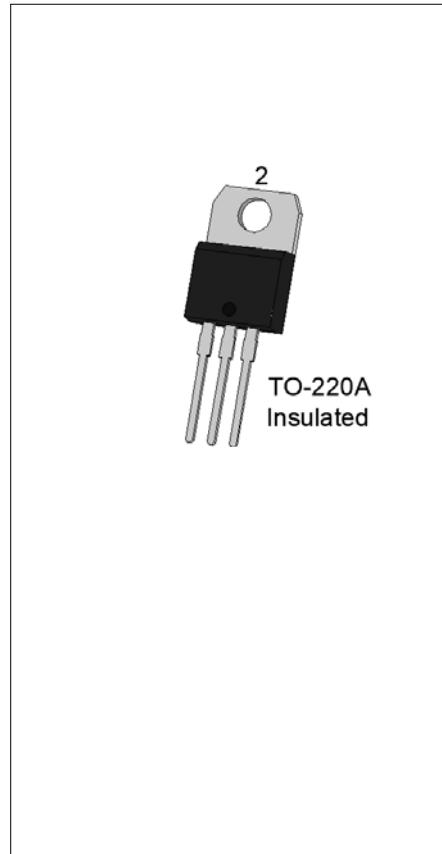


ACJT405-8A 4A TRIAC

Rev.A.1.0

The ACJT405-8A triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. The ACJT405-8A embeds a TVS structure to absorb the inductive turn-off energy such as those described in the IEC 61000-4-5 standards. By using an internal ceramic pad, ACJT405-8A provides a rated insulation voltage of 2500 VRMS, complying with UL standards (File ref: E252906).

Package TO-220A is RoHS compliant.



| Symbol | Value | Unit |
|-------------------|-------|------|
| $I_{T(RMS)}$ | 4 | A |
| V_{DRM}/V_{RRM} | 800 | V |
| $I_{GT} / /$ | 5/5/5 | mA |

| Parameter | Symbol | Value | Unit |
|---|--------------|---------|--------|
| Storage junction temperature range | T_{stg} | -40-150 | |
| Operating junction temperature range | T_j | -40-125 | |
| Repetitive peak off-state voltage ($T_j=25^\circ C$) | V_{DRM} | 800 | V |
| Repetitive peak reverse voltage ($T_j=25^\circ C$) | V_{RRM} | 800 | V |
| RMS on-state current ($T_c = 106^\circ C$) | $I_{T(RMS)}$ | 4 | A |
| Non repetitive surge peak on-state current (full cycle , $t_p=20ms$, $T_j=25^\circ C$) | I_{TSM} | 40 | A |
| Non repetitive surge peak on-state current (full cycle , $t_p=16.6ms$, $T_j=25^\circ C$) | | 44 | |
| I^2t value for fusing ($t_p=10ms$, $T_j=25^\circ C$) | I^2t | 8 | A^2s |
| Critical rate of rise of on-state current ($I_G=2 \times I_{GT}$, $f=100Hz$, $T_j=125^\circ C$) | dI/dt | 50 | A/s |
| Peak gate current ($t_p=20\mu s$, $T_j=125^\circ C$) | I_{GM} | 4 | A |

| | | | |
|--|-------------|-----|----|
| Average gate power dissipation ($T_j=125^\circ C$) | $P_{G(AV)}$ | 0.5 | W |
| Peak gate power | P_{GM} | 10 | W |
| Peak pulse voltage ($T_j=25^\circ C$; non-repetitive, off-state; FIG.7) | V_{pp} | 3 | kV |

($T_j=25^\circ C$ unless otherwise specified)

| Symbol | Test Condition | Quadrant | Value | | Unit |
|------------|---|----------|-------|-----|------|
| I_{GT} | $V_D=12V R_L=33\Omega$ | - - | MAX. | 5 | mA |
| V_{GT} | | - - | MAX. | 1 | V |
| V_{GD} | $V_D=V_{DRM} T_j=125^\circ C$ $R_L=3.3K\Omega$ | - - | MIN. | 0.2 | V |
| I_L | $I_G=1.2I_{GT}$ | - | MAX. | 15 | mA |
| | | | | 20 | |
| I_H | $I_T=100mA$ | | MAX. | 10 | mA |
| dV/dt | $V_D=540V$ Gate Open $T_j=125^\circ C$ | | MIN. | 200 | V/s |
| $(dI/dt)c$ | $(dV/dt)c=1$ $j=125^\circ C$ | | MIN. | 1.2 | A/ms |
| t_{on} | $I_G=10mA I_A=200mA I_R=20mA$ $T_j=25^\circ C$ | TYP. | 2 | s | |
| t_{off} | | | 20 | | |
| V_{CL} | $I_{CL}=0.1mA t_p=1ms$ | | MIN. | 850 | V |

| Symbol | Parameter | | Value(MAX.) | Unit | |
|-----------|--------------------|-------------------|-------------------|------|----|
| V_{TM} | $I_{TM}=5.6A$ | $t_p=380\mu s$ | $T_j=25^\circ C$ | 1.55 | V |
| V_{TO} | Threshold voltage | | $T_j=125^\circ C$ | 0.73 | V |
| R_D | Dynamic resistance | | $T_j=125^\circ C$ | 171 | |
| I_{DRM} | $V_D=V_{DRM}$ | $T_j=25^\circ C$ | | 5 | A |
| I_{RRM} | | $T_j=125^\circ C$ | | 0.25 | mA |

| Symbol | Parameter | Value | Unit |
|---------------|--------------------------|-------|------|
| $R_{th(j-c)}$ | junction to case (AC) | 3.3 | /W |
| $R_{th(j-a)}$ | junction to ambient (AC) | 60 | /W |

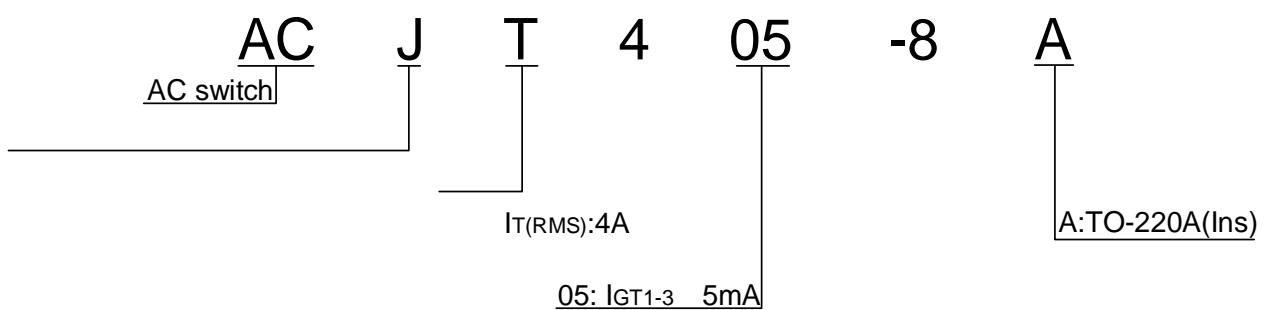


FIG.1 Maximum power dissipation versus RMS on-state current

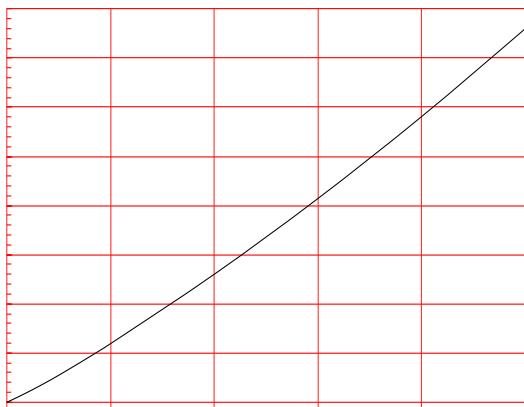


FIG.2: RMS on-state current versus case temperature

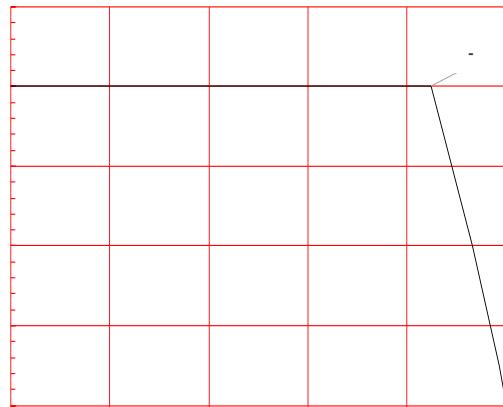


FIG.3: Surge peak on-state current versus number of cycles

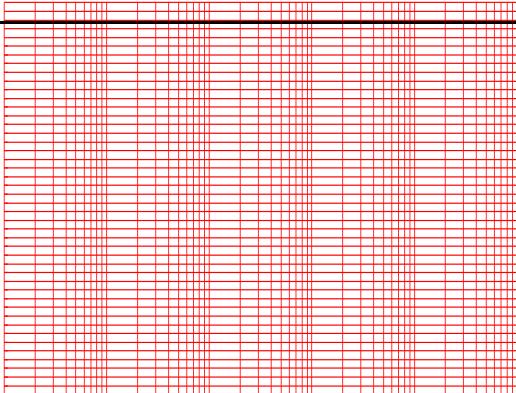
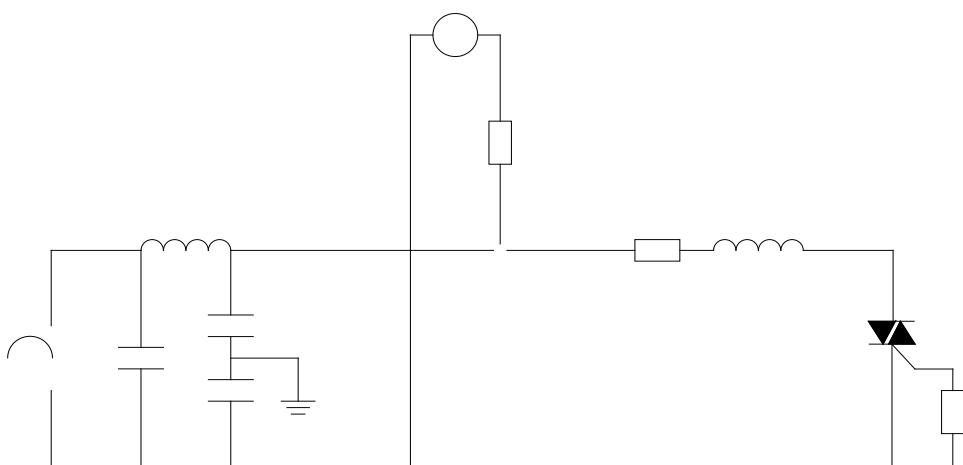


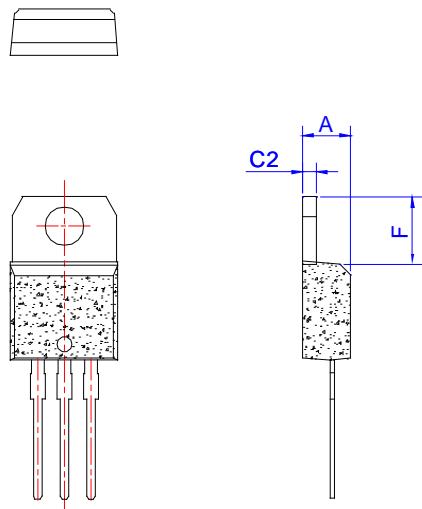
FIG.4: On-state characteristics

FIG.7 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



| Order code | Voltage V_{DRM}/V_{RRM} (V) | IGT(mA) | Package | Base qty. (pcs) | Delivery mode |
|------------|----------------------------------|---------|--------------|--------------------|------------------|
| ACJT405-8A | 800 | 5 | TO-220A(Ins) | 50 | Tube |

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